MOSFET – Dual, P-Channel with ESD Protection, Small Signal, SOT-563

-20 V, -430 mA

Features

- Low R_{DS(on)} Improving System Efficiency
- Low Threshold Voltage
- ESD Protected Gate
- Small Footprint 1.6 x 1.6 mm
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

Applications

- Load/Power Switches
- Power Supply Converter Circuits
- Battery Management
- Cell Phones, Digital Cameras, PDAs, Pagers, etc.

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted.)

Parameter			Symbol	Value	Unit
Drain-to-Source Voltage			V _{DSS}	-20	V
Gate-to-Source Voltage			V _{GS}	±6.0	V
Continuous Drain Current	Steady	$T_A = 25^{\circ}C$	_	-430	mA
(Note 1)	State	$T_A = 85^{\circ}C$	ID	-310	
Power Dissipation (Note 1)	Steady State		P _D	250	mW
Continuous Drain Current	t ≤ 5 s	$T_A = 25^{\circ}C$	I_	-455	mA
(Note 1)	1 2 3 3	$T_A = 85^{\circ}C$	ID	-328	
Power Dissipation (Note 1)	t ≤ 5 s		P _D	280	mW
Pulsed Drain Current	t _p =	10 μs	I _{DM}	-750	mA
Operating Junction and Storage Temperature			T _J , T _{STG}	-55 to 150	°C
Source Current (Body Diode)			Is	-350	mA
Lead Temperature for Soldering Purposes (1/8" from case for 10 s)			T _L	260	°C

THERMAL RESISTANCE RATINGS

Parameter	Symbol	Max	Unit
Junction-to-Ambient - Steady State (Note 1)			°C/W
Junction–to–Ambient – t ≤ 5 s (Note 1)	$R_{\theta JA}$	447	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

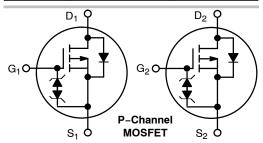
1. Surface mounted on FR4 board using 1 in. sq. pad size (Cu. area = 1.127 in. sq. [1 oz.] including traces).



ON Semiconductor®

www.onsemi.com

V _{(BR)DSS}	R _{DS(on)} Typ	I _D Max	
	0.5 Ω @ -4.5 V		
-20 V	0.6 Ω @ -2.5 V	–430 mA	
	1.0 Ω @ -1.8 V		



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MARKING DIAGRAM

SOT-563-6 CASE 463A

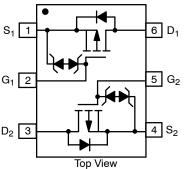


TU = Specific Device Code

M = Date Code

■ Pb-Free Package
(Note: Microdot may be in either location)

PINOUT: SOT-563



ORDERING INFORMATION

Device	Package	Shipping [†]	
NTZD3152PT1G	SOT-563	4000 / Tong 9 Dool	
NTZD3152PT1H	(Pb-Free)	4000 / Tape & Reel	
NTZD3152PT5H	SOT-563 (Pb-Free)	8000 / Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted.)

Parameter	Symbol	Test Condition		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
Drain-to-Source Breakdown Voltage	V _{(BR)DSS}	$V_{GS} = 0 \text{ V}, I_D = -250 \mu\text{A}$		-20			V
Drain-to-Source Breakdown Voltage Temperature Coefficient	V _{(BR)DSS} /T _J				18		mV/°C
Zero Gate Voltage Drain Current	I _{DSS}	V _{GS} = 0 V,	T _J = 25°C			-1.0	μΑ
		$V_{GS} = 0 V$, $V_{DS} = -16 V$	T _J = 125°C			-2.0	1
Gate-to-Source Leakage Current	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS}$	_S = ±4.5 V			±2.0	μΑ
ON CHARACTERISTICS (Note 2)							
Gate Threshold Voltage	V _{GS(TH)}	$V_{GS} = V_{DS}, I_{D}$	= -250 μA	-0.45		-1.0	V
Negative Threshold Temperature Coefficient	V _{GS(TH)} /T _J				-1.9		mV/°C
Drain-to-Source On Resistance	R _{DS(on)}	V _{GS} = -4.5 V, I _E	$V_{GS} = -4.5 \text{ V}, I_D = -430 \text{ mA}$		0.5	0.9	Ω
		V _{GS} = -2.5 V, I _E	₀ = -300 mA		0.6	1.2	1
		$V_{GS} = -1.8 \text{ V}, I_D = -150 \text{ mA}$			1.0	2.0	1
Forward Transconductance	9FS	$V_{DS} = -10 \text{ V}, I_D$	= -430 mA		1.0		S
CHARGES AND CAPACITANCES							
Input Capacitance	C _{ISS}	$V_{GS} = 0 \text{ V, f} = 1.0 \text{ MHz,}$ $V_{DS} = -16 \text{ V}$			105	175	pF
Output Capacitance	C _{OSS}				15	30	
Reverse Transfer Capacitance	C _{RSS}				10	20	
Total Gate Charge	Q _{G(TOT)}				1.7	2.5	nC
Threshold Gate Charge	Q _{G(TH)}	$V_{GS} = -4.5 \text{ V}, V_{DS} = -10 \text{ V},$ $I_{D} = -215 \text{ mA}$			0.1		
Gate-to-Source Charge	Q_{GS}				0.3		
Gate-to-Drain Charge	Q_{GD}				0.4		1
SWITCHING CHARACTERISTICS (Note	3)						
Turn-On Delay Time	t _{d(on)}				10		ns
Rise Time	t _r	V_{GS} = -4.5 V, V_{DD} = -10 V, I_D = -215 mA, R_G = 10 Ω			12		
Turn-Off Delay Time	t _{d(off)}				35		
Fall Time	t _f				19		
DRAIN-SOURCE DIODE CHARACTERI	STICS						
Forward Diode Voltage	V _{SD}	$V_{GS} = 0 \text{ V},$ $I_{S} = -350 \text{ mA}$	T _J = 25°C		-0.8	-1.2	V
Reverse Recovery Time	t _{RR}	$V_{GS} = 0 \text{ V, } dI_{SD}/c$	t = 100 A/μs, 0 mA		13		ns

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

2. Pulse Test: pulse width $\leq 300~\mu s$, duty cycle $\leq 2\%$.

3. Switching characteristics are independent of operating junction temperatures.

TYPICAL PERFORMANCE CURVES (T $_{J}$ = 25°C unless otherwise noted)

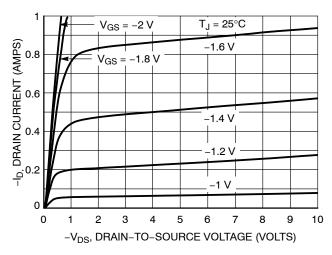


Figure 1. On-Region Characteristics

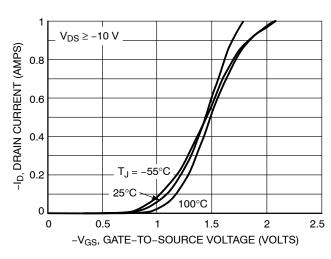


Figure 2. Transfer Characteristics

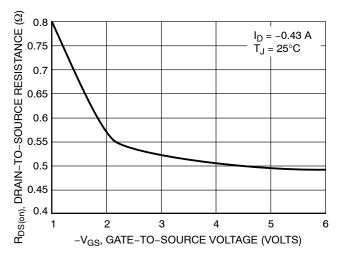


Figure 3. On-Resistance vs. Gate-to-Source Voltage

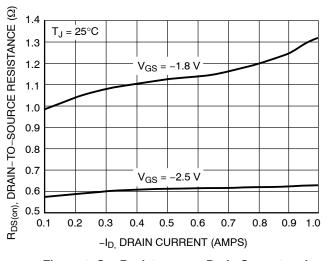


Figure 4. On-Resistance vs. Drain Current and Gate Voltage

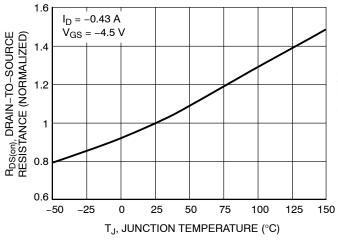


Figure 5. On–Resistance Variation with Temperature

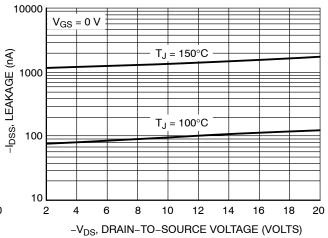


Figure 6. Drain-to-Source Leakage Current vs. Voltage

TYPICAL PERFORMANCE CURVES (T_J = 25°C unless otherwise noted)

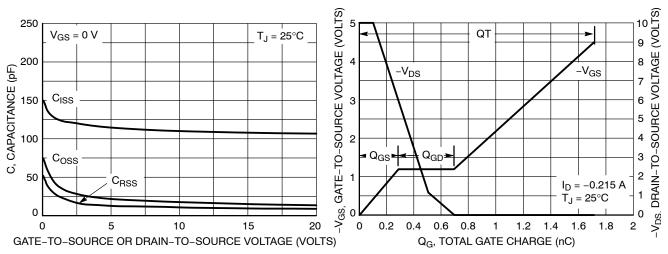


Figure 7. Capacitance Variation

Figure 8. Gate-to-Source and Drain-to-Source Voltage vs. Total Charge

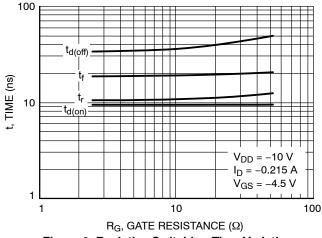


Figure 9. Resistive Switching Time Variation vs. Gate Resistance

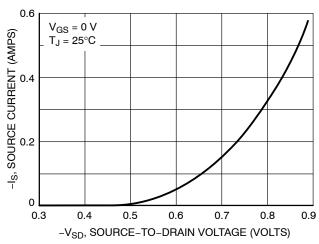


Figure 10. Diode Forward Voltage vs. Current

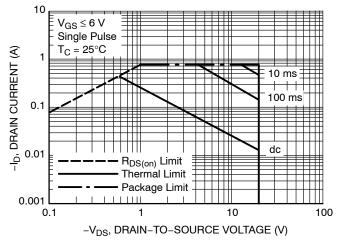


Figure 11. Safe Operating Area

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS



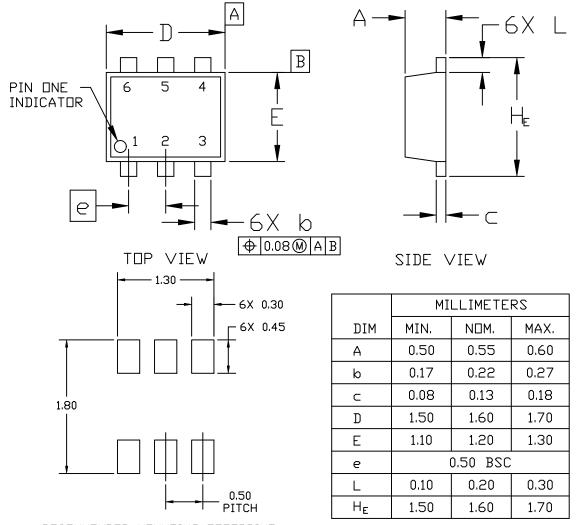


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DATE 26 JAN 2021

NOTES:

- I. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2009.
- 2. CONTROLLING DIMENSION: MILLIMETERS
- 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.



RECOMMENDED MOUNTING FOOTPRINT*

For additional information on our Pb-Free strategy and soldering details, please download the DN Semiconductor Soldering and Mounting Techniques Reference Manual, SDLDERRM/D.

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CASE 463A ISSUE H

DATE 26 JAN 2021

STYLE 1: PIN 1. EMITTER 1 2. BASE 1 3. COLLECTOR 2 4. EMITTER 2 5. BASE 2 6. COLLECTOR 1	STYLE 2: PIN 1. EMITTER 1 2. EMITTER 2 3. BASE 2 4. COLLECTOR 2 5. BASE 1 6. COLLECTOR 1	STYLE 3: PIN 1. CATHODE 1 2. CATHODE 1 3. ANODE/ANODE 2 4. CATHODE 2 5. CATHODE 2 6. ANODE/ANODE 1
STYLE 4: PIN 1. COLLECTOR 2. COLLECTOR 3. BASE 4. EMITTER 5. COLLECTOR 6. COLLECTOR	STYLE 5: PIN 1. CATHODE 2. CATHODE 3. ANODE 4. ANODE 5. CATHODE 6. CATHODE	STYLE 6: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE
STYLE 7: PIN 1. CATHODE 2. ANODE 3. CATHODE 4. CATHODE 5. ANODE 6. CATHODE	STYLE 8: PIN 1. DRAIN 2. DRAIN 3. GATE 4. SDURCE 5. DRAIN 6. DRAIN	STYLE 9: PIN 1. SDURCE 1 2. GATE 1 3. DRAIN 2 4. SDURCE 2 5. GATE 2 6. DRAIN 1
STYLE 10: PIN 1. CATHODE 1 2. N/C 3. CATHODE 2 4. ANODE 2 5. N/C 6. ANODE 1	STYLE 11: PIN 1. EMITTER 2 2. BASE 2 3. COLLECTOR 1 4. EMITTER 1 5. BASE 1 6. COLLECTOR 2	

GENERIC MARKING DIAGRAM*



XX = Specific Device CodeM = Month Code= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

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